

4th European School on Crystal Growth

Jachranka near Warsaw, 17-21 July 2024

Programme

	Wednesday 17 July	Thursday 18 July	Friday 19 July	Saturday 20 July	Sunday 21 July
09:00-10:30		Zbigniew Gałązka Bulk Crystal Growth and Physical Properties of Transparent Semiconductor Oxides	Ghazala Sadiq Insights from small molecules - a structural informatics workflow to assess solid form	Filip Tuomisto Positron annihilation spectroscopy: characterizing vacancy defects in crystals	Dorota Pawlak New composite materials for photonics, energy and other applications
10:30-11:00		break			
11:00-12:30		Christiane Frank-Rotsch Semiconductor bulk crystal growth by vertical gradient freeze (VGF) method	Lutz Kirste X-ray Diffraction Metrology of Semiconductor Substrates and Epitaxial Thin Films for Device Fabrication	Thierry Duffar Numerical simulation to help crystal growth research and production	Grzegorz Muzioł Novel Concepts in optoelectronics devices based on GaN
12:30-14:00		lunch			
14:00-15:30		Gathering of participants at Unipress, Warsaw	Nicola Lovergine Vapor Phase Epitaxy of Semiconductors	George Dimitrakopoulos Defect and strain engineering in epitaxial semiconductors: Insight from topological analysis and quantitative electron microscopy	Paweł Strąk Abinitio modelling of surfaces, crystal growth and defects
15:30-16:00	break				
16:00-17:30	Tomasz Sochacki The power of GaN: Crystallization for tomorrow's needs	Eleftherios Iliopoulos III-Nitrides Molecular Beam Epitaxy: Fundamentals, Kinetics and Applications	Poster presentations of participants	Round table discussion on the creation of a spin-off	
	Travel to Jachranka			School Dinner	